NSN 5961-01-191-1301

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-191-1301 **Inclosure Material:** Glass **Overall Length:** 0.350 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.240 inches **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 25.00 milliamperes all primaries horsepower metric **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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